#### MOSFET - Losses

### 1) Conduction

$$P_{cond-H} = R_{ds} I_{out} D$$

$$R_{ds} = 1.78 \Lambda L$$

$$I_{cond-L} = R_{ds} I_{out} (1-D)$$

$$D = \% 20.$$

## 2) Switching

$$P_{SW} = 120 \times (2.4) \times (43 \times 10^{-9}) \times 10^{5}$$
  
= 1.23 W

$$t = 21 \text{ ns}$$

High side mosfet 
$$\rightarrow P = 0.66W + 0.615W = 1.275W$$
  
 $\rightarrow P = 2.64W + 0.615 = 3.255W$ 

# Without Hootsink

Diode Losses

### 1) Conduction

Prond = V forward \* I diode = 1.10 x (0.5) = 0.55 W

2) Reverse Rossey Losses Qrr = 50 nc

Pri = Vierese x I = Vierere xfsw x Qrr = Vierese x fsw xtrr x Irrx 1

Pr = 260 × 10 5 × 50 × 10 = 1.2 W Tolol -> 1.85W

Pro= 260x +0 x 312,5 x 109

Without Hostsihle

Trunc = Tomb + Pross Ro = 25 + 1.85 x 53 = 123.05 < 150